

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL MOS TYPE

2SK2855

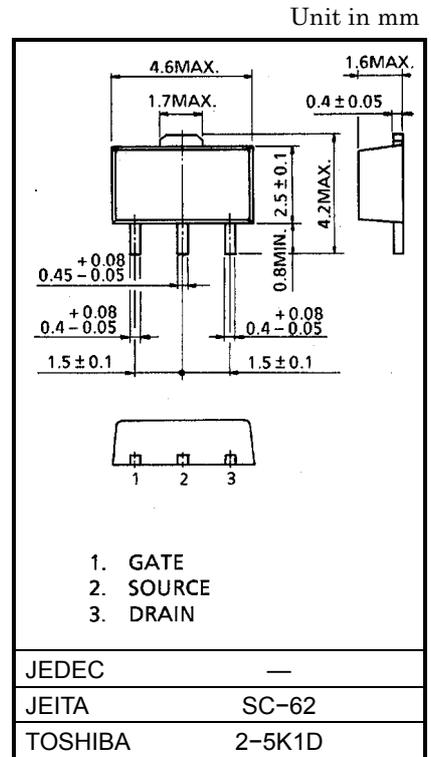
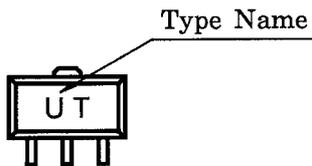
UHF BAND AMPLIFIER APPLICATION

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Drain-Source Voltage	V_{DSS}	10	V
Gate-Source Voltage	V_{GSS}	±6	V
Drain Current	I_D	1.0	A
Drain Power Dissipation	P_D^*	0.5	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

*: $T_c = 25^\circ\text{C}$ When mounted on a 1.6mm glass epoxy PCB

MARKING



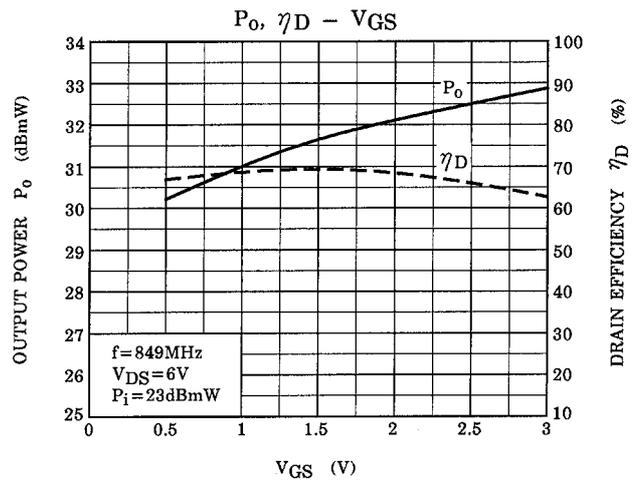
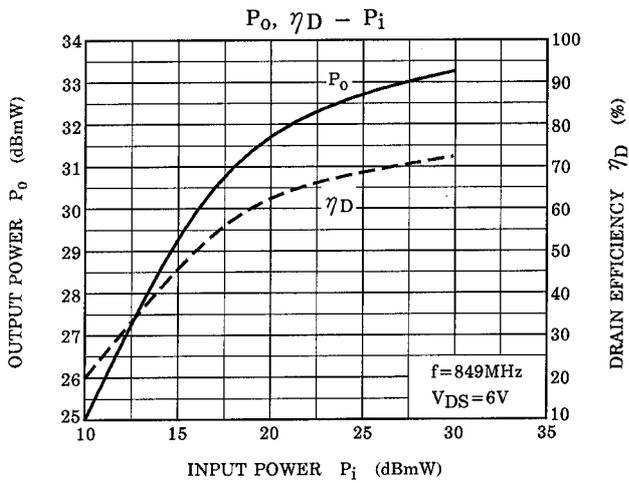
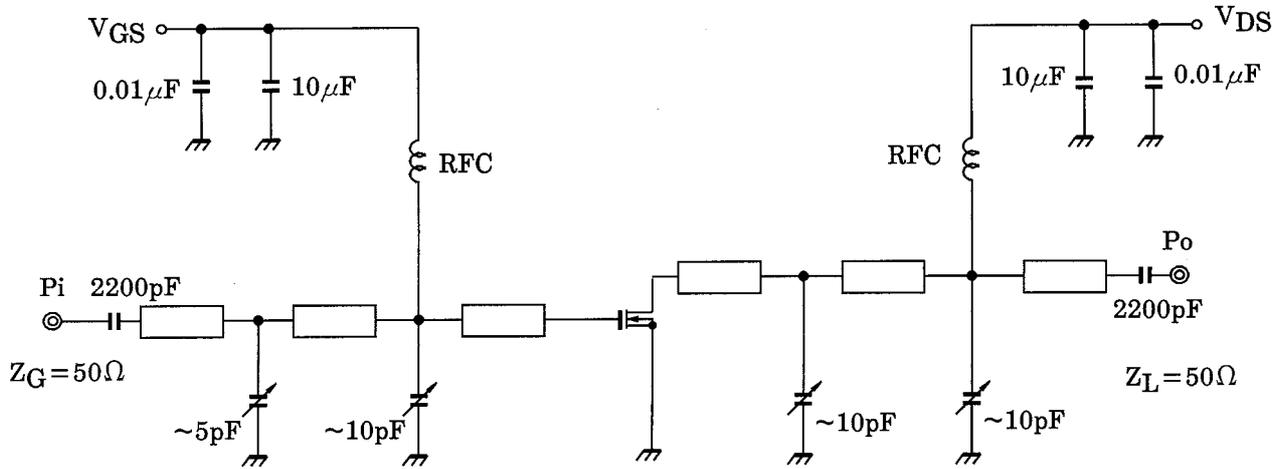
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Power	P_O	$V_{DS} = 6V, f = 849\text{MHz}$ $P_i = 23\text{dBmW}$	31	—	—	dBmW
Drain Efficiency	η_D	$V_{DS} = 6V, f = 849\text{MHz}$ $P_i = 23\text{dBmW}, P_O = 31\text{dBmW}$	55	—	—	%
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0, I_D = 1\mu\text{A}$	10	—	—	V
Drain Cut-off Current	I_{DSS}	$V_{DS} = 6V, V_{GS} = 0$	—	—	100	nA
Threshold Voltage	V_{th}	$V_{DS} = 6V, I_D = 500\mu\text{A}$	1.0	1.4	1.8	V
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = 6V, V_{DS} = 0$	—	—	±100	nA

CAUTION

This transistor is the electrostatic sensitive device.
Please handle with caution.

RF OUTPUT POWER TEST FIXTURE



CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.

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